

Effect of uniaxial magnetic anisotropy on charge transport in a junction with a precessing anisotropic molecular spin

Milena Filipović

Institute of Physics Belgrade, University of Belgrade, Pregrevica 118, 11080 Belgrade, Serbia

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Anisotropic molecular magnets can be employed to manipulate charge transport in molecular nanojunctions. The charge transport through an electronic level connected to source and drain metallic contacts and exchange-coupled with a precessing anisotropic molecular spin in a constant external magnetic field is studied here. Both the magnetic field and the uniaxial magnetic anisotropy parameter of the molecular spin control the total precession frequency. The Keldysh nonequilibrium Green's functions method is used to derive expressions for charge current and current noise. The precessing molecular magnetization drives inelastic tunnelling processes between electronic quasienergy levels. The dc-bias voltages allow to unveil the quasienergy levels, Larmor frequency and the anisotropy parameter, through characteristics of charge-transport measurements involving features such as steps, peaks and dips. Under zero-bias voltage conditions, for a sufficiently large anisotropy parameter that enables the decrease of the total precession frequency or change of the precession direction with respect to Larmor precession, the shot noise is reduced. Furthermore, it is possible to adjust the magnetic anisotropy parameter to suppress the precession frequency, leading to the suppression of shot noise. The results show that in the given setup, the charge current and shot noise can be controlled by the uniaxial magnetic anisotropy of the molecular magnet.

I. INTRODUCTION

Single-molecule magnets have gained much attention since the beginning of the new century due to the possibility to be used as constituent elements in spintronic devices for high-density information storage and quantum information processing.^{1–6} The key role in these applications plays the uniaxial magnetic anisotropy, characterized by parameter D , which leads to the bistability of the molecular spin states, with two degenerate ground states $\pm S$, separated by an energy barrier to spin reversal DS^2 (for integer spins) at low temperatures.^{2,3,7,8} Depending on the sign of the anisotropy parameter, there are two types of uniaxial anisotropy: easy-axis ($D > 0$), and easy-plane ($D < 0$) anisotropy.² For successful applications in magnetic storage, the energy barrier needs to be enhanced,⁹ but its increase cannot be accomplished by a simultaneous increase of the anisotropy parameter D and the ground state spin S , and the only way to control the barrier height is to modulate the value of D .^{10–13} On the other hand, in-plane and small magnetic anisotropy is desirable for applications in quantum information processing.¹⁴ In order to design magnetic molecules with desired characteristics, learning to control and manipulate the magnetic anisotropy parameter D is essential.

Charge transport through magnetic molecules has been studied both theoretically^{15–24} and experimentally.^{25–32} The studies have addressed various phenomena, such as e.g., Kondo effect,^{33–36} Pauli spin blockade,^{37–39} Coulomb blockade,^{25,40–42} molecular magnetization switching induced by electric current⁴³ or in contact with a superconducting lead,⁴⁴ and spin-dependent Seebeck and Peltier effect.^{45–48} The possibility to manipulate molecular magnetization by charge current has already been demonstrated experimentally.^{26–30,49}

It has been theoretically predicted that exchange interactions between molecular magnets can be electrically controlled.^{18,19} Magnetic anisotropy can be varied and controlled by various means such as, electrical current,^{15,41,50–53} electric field,^{41,54–57} molecular mechanical stretching,⁵⁸ and by ligand substitution.⁵⁹ High anisotropy barriers for spin reversal were observed in some isolated metal complexes, but due to their reactivity and instability, they are not suitable candidates to be exploited in magnetic storage.^{60–63} Also, new optical techniques of spin readout in single-molecule magnets have been investigated recently.^{64–66}

The nonequilibrium Green's functions technique^{67–69} has been used to derive various characteristics of quantum transport through single molecules and molecular magnets, such as charge current, current-current correlations, spin current, inelastic transport, heat current, etc.^{16,18–20,48,70–74} Charge-current noise in transport junctions arising from the discreteness of charge of conducting electrons is an exciting topic in nanophysics, since it can give us additional information about charge transport which is hidden from the current measurements.⁷⁵ Within the framework of nonequilibrium Green's functions technique, the effect of inelastic transport on shot noise has been studied,^{70,76–79} as well as current fluctuations in the transient regime.⁸⁰ It has been shown previously that spin-flip can lead to suppression^{76,81} or enhancement^{82,83} of the shot noise. The shot noise has been employed to give information on the e.g., energy of transmission channels,⁷⁵ fractional charges,⁸⁴ and Cooper pairs.⁸⁵ Recently, the nonequilibrium noise due to temperature gradient at zero-bias voltage has become an active research topic.^{86–90} Moreover, it has been demonstrated that negative values of this noise are a sign of spin-flip scattering due to temperature bias.⁹¹

The goal of this article is to theoretically study the charge transport through a single electronic energy level that may be an orbital of a molecular magnet or belong to a nearby quantum dot, in the presence of a precessing anisotropic molecular spin in a constant external magnetic field, connected to electric contacts. The precession frequency is contributed by the Larmor precession frequency and the uniaxial magnetic anisotropy parameter of the molecular spin, and kept undamped by external means. The spin of the itinerant electron in the electronic level and the molecular spin are coupled via exchange interaction. The charge current and current noise are calculated by means of the Keldysh nonequilibrium Green's functions technique.^{67–69} The shot noise of charge current is a result of the competition between correlations of currents with the same spins and correlations of currents with the opposite spins. Both elastic tunnelling, driven by the dc-bias voltage, and inelastic tunnelling involving a spin-flip, driven by the precessional motion of the anisotropic molecular spin, contribute to the charge transport. It is shown that by proper tuning of the uniaxial magnetic anisotropy parameter, the charge-current and shot noise can be manipulated. The energies of the channels available for electron transport are Floquet quasienergies, which are obtained by the Floquet theorem.^{92–95} They are dependent on the magnetic anisotropy of the molecular spin and can be varied accordingly. Both charge current and shot noise are saturated for sufficiently large magnetic anisotropy parameter at nonzero bias-voltage conditions. Similarly to our previous work where the precessing molecular spin was isotropic,⁷⁹ the peak-dip (dip-peak) features in the shot noise are manifestations of the destructive quantum interference⁹⁶ between the states connected with inelastic tunnelling, here involving absorption(emission) of an energy which is linearly dependent on the uniaxial magnetic anisotropy parameter. Finally, the results show that the shot noise at zero-bias conditions and zero temperature is reduced for chemical potentials of the metallic leads that enable inelastic tunnelling processes accompanied with spin-flips of itinerant electrons, if the uniaxial magnetic anisotropy parameter is sufficiently large to decrease the total precession frequency or change the direction of the molecular spin precession with respect to the external magnetic field. Moreover, the magnetic anisotropy parameter can suppress the precession frequency of the molecular magnetization, leading to zero shot noise.

The rest of the article is arranged in the following way. The model setup of the system is described in Sec. II. Theoretical formalism used to derive the results is given in Sec. III. The expressions for the charge current and the current noise are calculated by means of the Keldysh nonequilibrium Green's functions method.^{67–69} The results are shown and discussed in Sec. IV, where the effects of the uniaxial magnetic anisotropy of the molecular spin on the charge-transport properties at zero temperature are analysed. This section is followed by Sec. V in which the conclusions are presented.

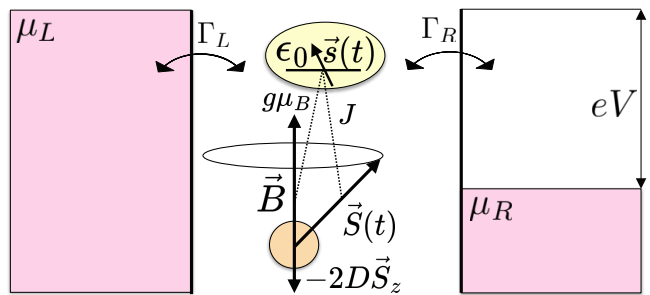


FIG. 1: (Color online) Tunneling through a single molecular orbital with energy ϵ_0 coupled to the anisotropic spin $\vec{S}(t)$ of a molecular magnet via exchange interaction with the coupling constant J , in the presence of a magnetic field \vec{B} , connected to two metallic leads with chemical potentials μ_L and μ_R . The applied bias voltage $eV = \mu_L - \mu_R$, with tunnel rates Γ_L and Γ_R , and the uniaxial anisotropy constant of the molecular magnet D . The spin of the molecule precesses around the magnetic field axis with modified frequency $\omega = \omega_L - 2DS_z$.

II. MODEL SETUP

The junction under consideration consists of a single molecular orbital of a molecular magnet, in the presence of a constant external magnetic field along z -axis, $\vec{B} = B\vec{e}_z$, coupled to two noninteracting metallic leads (see Fig. 1). The leads with chemical potentials μ_L (left) and μ_R (right) are unaffected by the magnetic field. The Hamiltonian describing the junction is given by $\hat{H} = \hat{H}_L + \hat{H}_R + \hat{H}_T + \hat{H}_{MO} + \hat{H}_S$. Here, the Hamiltonian of lead $\xi = L, R$ can be written as $\hat{H}_\xi = \sum_{k,\sigma} \epsilon_{k\xi} \hat{c}_{k\xi}^\dagger \hat{c}_{k\xi}$. The subscript $\sigma = \uparrow, \downarrow = 1, 2 = \pm 1$ denotes the spin-up or spin-down state of the electrons. The tunnel coupling between the molecular orbital and the leads is introduced by $\hat{H}_T = \sum_{k,\sigma,\xi} [V_{k\xi} \hat{c}_{k\xi}^\dagger \hat{d}_\sigma + V_{k\xi}^* \hat{d}_\sigma^\dagger \hat{c}_{k\xi}]$, with matrix element $V_{k\xi}$. Here, $\hat{c}_{k\xi}^\dagger$ ($\hat{c}_{k\xi}$) and \hat{d}_σ^\dagger (\hat{d}_σ) denote the creation (annihilation) operators of the electrons in the leads and the molecular orbital. The Hamiltonian of the molecular orbital is given by $\hat{H}_{MO} = \sum_\sigma \epsilon_0 \hat{d}_\sigma^\dagger \hat{d}_\sigma + (g\mu_B/\hbar) \hat{s}\vec{B} + J\hat{s}\vec{S}$, where the first term is the Hamiltonian of the noninteracting molecular orbital with energy ϵ_0 . The second term describes the electronic spin in the molecular orbital, $\hat{s} = (\hbar/2) \sum_{\sigma\sigma'} (\hat{\sigma})_{\sigma\sigma'} \hat{d}_\sigma^\dagger \hat{d}_{\sigma'}$, in the presence of the magnetic field \vec{B} . The vector of the Pauli matrices is given by $\hat{\sigma} = (\hat{\sigma}_x, \hat{\sigma}_y, \hat{\sigma}_z)^T$, while g and μ_B are the gyromagnetic ratio of the electron and the Bohr magneton. The third term in the Hamiltonian of the orbital represents the exchange interaction between the electronic spin and the spin of the magnetic molecule, where J is the constant of the exchange coupling. The term $\hat{H}_S = g\mu_B \hat{S}\vec{B} - D\hat{S}_z^2$ represents the Hamiltonian of the anisotropic molecular spin $\hat{S} = \hat{S}_x\vec{e}_x + \hat{S}_y\vec{e}_y + \hat{S}_z\vec{e}_z$, where D is the uniaxial magnetic anisotropy constant. We assume for simplicity, that g factor of the molecular spin equals that of a free electron.

Assuming that the spin of the molecular magnet is large and that it can be considered as a classical variable \vec{S} , with constant length $S = |\vec{S}| \gg \hbar$, where $\vec{S} = \langle \hat{S} \rangle$ is the expectation value of the molecular spin operator, its dynamics is given by the Heisenberg equation of motion $\dot{\vec{S}} = \langle \dot{\hat{S}} \rangle = (i/\hbar) \langle [\hat{H}, \hat{S}] \rangle$. Neglecting the quantum fluctuations and using external means, such as radiofrequency fields,⁹⁷ to compensate for the loss of the molecular magnetic energy due to its interaction with the itinerant electrons, so that the molecular spin dynamics remains unaffected by the exchange interaction, the equation $\dot{\vec{S}} = g\mu_B \vec{B} \times \vec{S} - 2DS_z \times \vec{S}$ is obtained. The molecular spin precesses around z -axis, with frequency $\omega = \omega_L - 2DS_z$, where $\omega_L = g\mu_B B$ is the Larmor precession frequency in the external magnetic field \vec{B} , while $-2DS_z$ is the contribution of the uniaxial anisotropy to the precession frequency ω . The motion of the molecular spin is then given by $\vec{S}(t) = S_\perp \cos(\omega t) \vec{e}_x + S_\perp \sin(\omega t) \vec{e}_y + S_z \vec{e}_z$, where θ is the tilt angle between z -axis and \vec{S} , $S_\perp = S \sin(\theta)$ and $S_z = S \cos(\theta)$. Although the motion of the molecular spin is kept precessional externally,⁹⁷ the molecular magnet itself pumps charge current into the leads, thus affecting the transport properties of the junction.

III. THEORETICAL FORMALISM

A. Charge Current

The charge-current operator of the contact ξ is given by the Heisenberg equation^{68,69}

$$\hat{I}_\xi(t) = -e \frac{d\hat{N}_\xi}{dt} = -e \frac{i}{\hbar} [\hat{H}, \hat{N}_\xi], \quad (1)$$

where $\hat{N}_\xi = \sum_{k,\sigma} \hat{c}_{k\sigma\xi}^\dagger \hat{c}_{k\sigma\xi}$ represents the charge occupation number operator of the contact ξ , while $[\cdot, \cdot]$ denotes the commutator. The average charge current from the lead ξ to the molecular orbital is then given by

$$I_\xi(t) = -e \left\langle \frac{d\hat{N}_\xi}{dt} \right\rangle = -e \frac{i}{\hbar} \langle [\hat{H}, \hat{N}_\xi] \rangle. \quad (2)$$

Using the Keldysh nonequilibrium Green's functions technique, the charge current can be calculated as^{68,69}

$$I_\xi(t) = 2e \operatorname{Re} \int dt' \operatorname{Tr} \{ \hat{G}^r(t, t') \hat{\Sigma}_\xi^<(t', t) + \hat{G}^<(t, t') \hat{\Sigma}_\xi^a(t', t) \}, \quad (3)$$

in units in which $\hbar = e = 1$. The retarded, advanced, lesser and greater self-energies from the tunnel coupling between the molecular orbital and contact ξ are denoted by $\hat{\Sigma}_\xi^{r,a,<,>}(t, t')$. Their matrix elements are diagonal in the electron spin space with respect to the basis of the eigenstates of \hat{s}_z , with nonzero matrix elements given by $\Sigma_\xi^{r,a,<}(t, t') = \sum_k V_{k\xi} g_{k\xi}^{r,a,<,>}(t, t') V_{k\xi}^*$,

where $g_{k\xi}^{r,a,<,>}(t, t')$ represent the retarded, advanced, lesser and greater Green's functions of the electrons in the lead ξ . The Green's functions of the electrons in the molecular orbital are given by $\hat{G}^{r,a,<,>}(t, t')$, with matrix elements $G_{\sigma\sigma'}^{r,a}(t, t') = \mp i\theta(\pm t \mp t') \langle \{ \hat{d}_\sigma(t), \hat{d}_{\sigma'}^\dagger(t') \} \rangle$, while $G_{\sigma\sigma'}^<(t, t') = i \langle \hat{d}_{\sigma'}^\dagger(t') \hat{d}_\sigma(t) \rangle$ and $G_{\sigma\sigma'}^>(t, t') = -i \langle \hat{d}_\sigma(t) \hat{d}_{\sigma'}^\dagger(t') \rangle$, where $\{ \cdot, \cdot \}$ denotes the anticommutator. Applying the double Fourier transformations in Eq. (3equation.3.3), one obtains

$$I_\xi(t) = -2e\Gamma_\xi \operatorname{Im} \int \frac{d\epsilon}{2\pi} \int \frac{d\epsilon'}{2\pi} e^{-i(\epsilon-\epsilon')t} \times \operatorname{Tr} \left\{ f_\xi(\epsilon') \hat{G}^r(\epsilon, \epsilon') + \frac{1}{2} \hat{G}^<(\epsilon, \epsilon') \right\}, \quad (4)$$

where the tunnel coupling between the molecular orbital and contact ξ , $\Gamma_\xi(\epsilon) = 2\pi \sum_k |V_{k\xi}|^2 \delta(\epsilon - \epsilon_{k\xi})$, is energy independent in the wide-band limit and considered constant. The Fermi-Dirac distribution of the electrons in the lead ξ is given by $f_\xi(\epsilon) = [e^{(\epsilon-\mu_\xi)/k_B T} + 1]^{-1}$, with k_B the Boltzmann constant and T the temperature.

The matrix components of the retarded Green's function \hat{G}^r of the electrons in the molecular orbital, can be obtained by applying Dyson's expansion and analytic continuation rules.⁶⁹ Their double Fourier transforms read^{98,99}

$$G_{\sigma\sigma}^r(\epsilon, \epsilon') = \frac{2\pi\delta(\epsilon - \epsilon') G_{\sigma\sigma}^{0r}(\epsilon)}{1 - \gamma^2 G_{\sigma\sigma}^{0r}(\epsilon) G_{-\sigma-\sigma}^{0r}(\epsilon_\sigma)}, \quad (5)$$

$$G_{\sigma-\sigma}^r(\epsilon, \epsilon') = \frac{2\pi\gamma\delta(\epsilon_\sigma - \epsilon') G_{\sigma\sigma}^{0r}(\epsilon) G_{-\sigma-\sigma}^{0r}(\epsilon_\sigma)}{1 - \gamma^2 G_{\sigma\sigma}^{0r}(\epsilon) G_{-\sigma-\sigma}^{0r}(\epsilon_\sigma)}, \quad (6)$$

where the abbreviation $\epsilon_\sigma = \epsilon - \sigma\omega = \epsilon - \sigma(\omega_L - 2DS_z)$ is used, and $\gamma = JS \sin(\theta)/2$. Applying the double Fourier transformations to the Keldysh equation, the lesser and greater Green's functions can be calculated as $\hat{G}^{<,>}(\epsilon, \epsilon') = \int d\epsilon'' \hat{G}^r(\epsilon, \epsilon'') \hat{\Sigma}^{<,>}(\epsilon'', \epsilon') \hat{G}^a(\epsilon'', \epsilon')/2\pi$.⁶⁹ where $\Sigma^<(\epsilon) = i \sum_\xi \Gamma_\xi f_\xi(\epsilon)$, $\Sigma^>(\epsilon) = i \sum_\xi \Gamma_\xi (f_\xi(\epsilon) - 1)$ and $\hat{G}^a(\epsilon, \epsilon') = [\hat{G}^r(\epsilon', \epsilon)]^\dagger$. The retarded Green's function \hat{G}^{0r} of the electrons in the orbital in the presence of only the static spin component S_z along the axis of the external magnetic field can be found using the equation of motion technique,¹⁰⁰ and after applying the Fourier transformations, one writes $\hat{G}^{0r}(\epsilon) = [\epsilon - \epsilon_0 - \Sigma^r - \hat{\sigma}_z(g\mu_B B + JS_z)/2]^{-1}$,^{43,98} where $\Sigma^{r,a} = \mp i\Gamma/2$ and $\Gamma = \sum_\xi \Gamma_\xi$. Finally, using Eqs. (4)-(6), and obtaining $\hat{G}^<(\epsilon, \epsilon')$ from the Keldysh equation, the average charge current from the contact ξ can be written as

$$I_\xi = \frac{e\Gamma_\xi \Gamma_\zeta}{\hbar} \int \frac{d\epsilon}{2\pi} [f_\xi(\epsilon) - f_\zeta(\epsilon)] \times \sum_{\substack{\sigma\sigma' \\ \sigma \neq \sigma'}} \frac{|G_{\sigma\sigma'}^{0r}(\epsilon)|^2 [1 + \gamma^2 |G_{\sigma'\sigma'}^{0r}(\epsilon + \sigma'\omega_L - 2\sigma' DS_z)|^2]}{|1 - \gamma^2 G_{\sigma\sigma}^{0r}(\epsilon) G_{\sigma'\sigma'}^{0r}(\epsilon + \sigma'\omega_L - 2\sigma' DS_z)|^2}, \quad (7)$$

with $\xi \neq \zeta$. In the limit $DS_z \ll \omega_L$, Eq. (7) reduces to the previously calculated expression for the charge current.⁷⁹

B. Density of States in the Molecular Orbital

The positions of the resonant transmission channels available for electron transport in the molecular orbital can be obtained from the density of states in the orbital

$$\rho(\epsilon) = -\frac{1}{\pi} \sum_{\sigma=\pm 1} \text{Im} \left\{ \frac{G_{\sigma\sigma}^{0r}(\epsilon)}{1 - \gamma^2 G_{\sigma\sigma}^{0r}(\epsilon) G_{-\sigma-\sigma}^{0r}(\epsilon)} \right\}. \quad (8)$$

Taking into account that the Hamiltonian of the molecular orbital is a periodic function of time $\hat{H}_{MO}(t) = \hat{H}_{MO}(t + \mathcal{T})$, with $\mathcal{T} = 2\pi/\omega$, the Floquet quasienergy levels ϵ_i , $i = 1, 2, 3, 4$, at which the resonant transmission channels are located, can be calculated using the Floquet theorem.⁹²⁻⁹⁵ As the Floquet Hamiltonian matrix is block diagonal, for quasienergies within the interval $[0, \omega)$ a block is given by

$$\begin{pmatrix} \lambda_1 - \omega & JS_{\perp}/2 \\ JS_{\perp}/2 & \lambda_2 \end{pmatrix}, \quad (9)$$

where $\lambda_{1,2} = \epsilon_0 \pm (\omega_L + JS_z)/2$. The eigenvalues of the matrix (9) are quasienergy levels ϵ_1 and ϵ_3 , while $\epsilon_2 = \epsilon_1 + \omega$ and $\epsilon_4 = \epsilon_3 + \omega$. They are given by

$$\epsilon_{1,3} = \epsilon_0 - \frac{\omega_L}{2} + DS_z \pm \sqrt{D(D+J)S_z^2 + \left(\frac{JS}{2}\right)^2}, \quad (10)$$

$$\epsilon_{2,4} = \epsilon_0 + \frac{\omega_L}{2} - DS_z \pm \sqrt{D(D+J)S_z^2 + \left(\frac{JS}{2}\right)^2}. \quad (11)$$

In the molecular orbital, an electron with energy $\epsilon_1(\epsilon_2)$ or $\epsilon_3(\epsilon_4)$ can absorb (emit) an energy equal to one energy quantum ω and flip its spin, due to the precessional motion of the anisotropic molecular spin, ending up in the quasienergy level with energy $\epsilon_2(\epsilon_1)$ or $\epsilon_4(\epsilon_3)$, so that the state with quasienergy $\epsilon_1(\epsilon_3)$ is coupled with the opposite-spin state with quasienergy $\epsilon_2(\epsilon_4)$.

C. Noise of Charge Current

Additional properties of the charge transport in the junction can be obtained by analysing the charge-current noise. In view of the fact that the nonzero commutator in Eq. (1) is generated by the tunnelling Hamiltonian \hat{H}_T , the charge current operator $\hat{I}_{\xi}(t)$ can be written as

$$\hat{I}_{\xi}(t) = e \frac{i}{\hbar} \sum_{\sigma} \hat{I}_{\xi\sigma}(t), \quad (12)$$

with the operator component $\hat{I}_{\xi\sigma}(t)$ given by

$$\hat{I}_{\xi\sigma}(t) = \sum_k [V_{k\xi} \hat{c}_{k\sigma\xi}^{\dagger}(t) \hat{d}_{\sigma}(t) - V_{k\xi}^* \hat{d}_{\sigma}^{\dagger}(t) \hat{c}_{k\sigma\xi}(t)]. \quad (13)$$

The fluctuation operator of the charge current in contact ξ is given by

$$\delta \hat{I}_{\xi}(t) = \hat{I}_{\xi}(t) - \langle \hat{I}_{\xi}(t) \rangle. \quad (14)$$

The correlation between fluctuations of currents in leads ξ and ζ , known as nonsymmetrized charge-current noise is written as^{69,75}

$$S_{\xi\zeta}(t, t') = \langle \delta \hat{I}_{\xi}(t) \delta \hat{I}_{\zeta}(t') \rangle. \quad (15)$$

With the help of Eqs. (12)-(14), one obtains the noise as

$$S_{\xi\zeta}(t, t') = -\frac{e^2}{\hbar^2} \sum_{\sigma\sigma'} S_{\xi\zeta}^{\sigma\sigma'}(t, t'), \quad (16)$$

with $S_{\xi\zeta}^{\sigma\sigma'}(t, t') = \langle \delta \hat{I}_{\xi\sigma}(t) \delta \hat{I}_{\zeta\sigma'}(t') \rangle$. Applying Wick's theorem¹⁰¹ and Langreth analytical continuation rules,¹⁰² the correlation functions $S_{\xi\zeta}^{\sigma\sigma'}(t, t')$ introduced in Eq. (16) can be calculated.^{69,80} Using the Fourier transforms of Green's functions $G_{\sigma\sigma'}^{r,a,<,>}(\epsilon, \epsilon')$ and self-energies $\Sigma_{\xi}^{r,a,<,>}(\epsilon)$, the charge-current noise becomes

$$\begin{aligned} S_{\xi\zeta}(t, t') = & -\frac{e^2}{\hbar^2} \sum_{\sigma\sigma'} \left\{ \int \frac{d\epsilon_1}{2\pi} \int \frac{d\epsilon_2}{2\pi} \int \frac{d\epsilon_3}{2\pi} \int \frac{d\epsilon_4}{2\pi} e^{-i(\epsilon_1 - \epsilon_2)t} e^{i(\epsilon_3 - \epsilon_4)t'} \right. \\ & \times \left\{ [G_{\sigma\sigma'}^r(\epsilon_1, \epsilon_3) \Sigma_{\zeta}^>(\epsilon_3) + 2G_{\sigma\sigma'}^>(\epsilon_1, \epsilon_3) \Sigma_{\zeta}^a] [G_{\sigma'\sigma}^r(\epsilon_4, \epsilon_2) \Sigma_{\xi}^<(\epsilon_2) + 2G_{\sigma'\sigma}^<(\epsilon_4, \epsilon_2) \Sigma_{\xi}^a] \right. \\ & + [\Sigma_{\xi}^>(\epsilon_1) G_{\sigma\sigma'}^a(\epsilon_1, \epsilon_3) + 2G_{\sigma\sigma'}^>(\epsilon_1, \epsilon_3) \Sigma_{\xi}^r] [\Sigma_{\zeta}^<(\epsilon_4) G_{\sigma'\sigma}^a(\epsilon_4, \epsilon_2) + 2G_{\sigma'\sigma}^<(\epsilon_4, \epsilon_2) \Sigma_{\zeta}^r] \\ & \left. + 4\Sigma_{\xi}^r \Sigma_{\zeta}^a G_{\sigma\sigma'}^>(\epsilon_1, \epsilon_3) G_{\sigma'\sigma}^<(\epsilon_4, \epsilon_2) \right\} \\ & - \delta_{\xi\zeta} \delta_{\sigma\sigma'} \int \frac{d\epsilon_1}{2\pi} \int \frac{d\epsilon_2}{2\pi} \int \frac{d\epsilon_3}{2\pi} \\ & \times \left\{ e^{-i(\epsilon_1 - \epsilon_3)t} e^{i(\epsilon_2 - \epsilon_3)t'} G_{\sigma\sigma'}^>(\epsilon_1, \epsilon_2) \Sigma_{\xi}^<(\epsilon_3) \right. \\ & \left. + e^{-i(\epsilon_1 - \epsilon_3)t} e^{i(\epsilon_1 - \epsilon_2)t'} \Sigma_{\xi}^>(\epsilon_1) G_{\sigma'\sigma}^<(\epsilon_2, \epsilon_3) \right\} \left. \right\}. \quad (17) \end{aligned}$$

The resulting noise depends only on the time difference $\tau = t - t'$, and its power spectrum is given by

$$S_{\xi\zeta}(\Omega) = \int d\tau e^{i\Omega\tau} S_{\xi\zeta}(\tau). \quad (18)$$

The charge current given by Eq. (7) is conserved, imply-

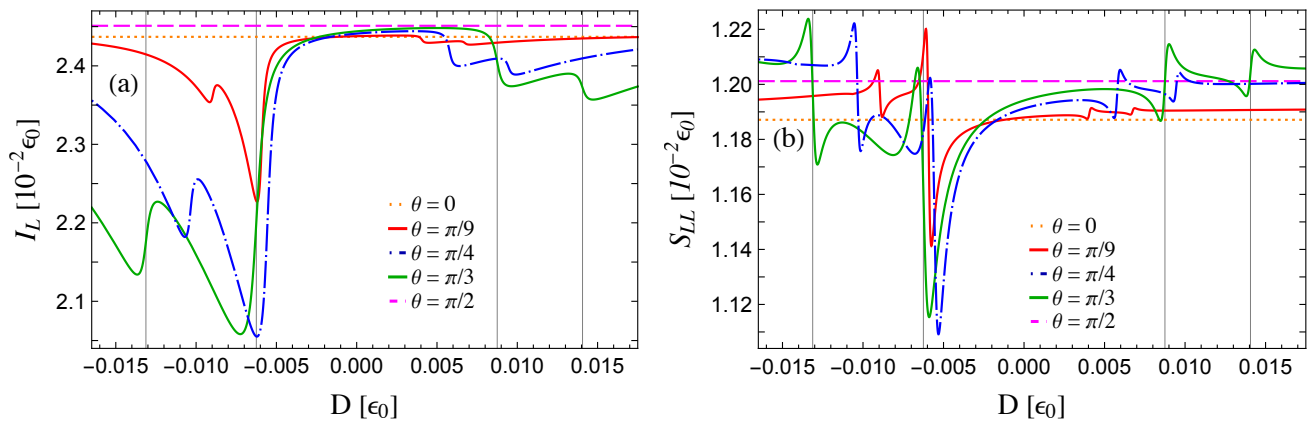


FIG. 2: (Color online) (a) Charge current I_L and (b) autocorrelation shot noise S_{LL} as functions of the uniaxial magnetic anisotropy parameter D for different tilt angles θ , at zero temperature, with $\vec{B} = B\vec{e}_z$. The chemical potentials of the leads are equal to: $\mu_L = 2.5\epsilon_0$ and $\mu_R = 0$. The other parameters are set to: $\Gamma = 0.05\epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $\omega_L = 0.5\epsilon_0$, $J = 0.01\epsilon_0$, $S = 100$. Grid lines for $\theta = \pi/3$ (green line), are positioned at $D = -0.01312\epsilon_0$ ($\mu_L = \epsilon_2$), $D = -0.00625\epsilon_0$ ($\mu_R = \epsilon_3$), $D = 0.00875\epsilon_0$ ($\mu_R = \epsilon_4$), and $D = 0.01406\epsilon_0$ ($\mu_L = \epsilon_1$).

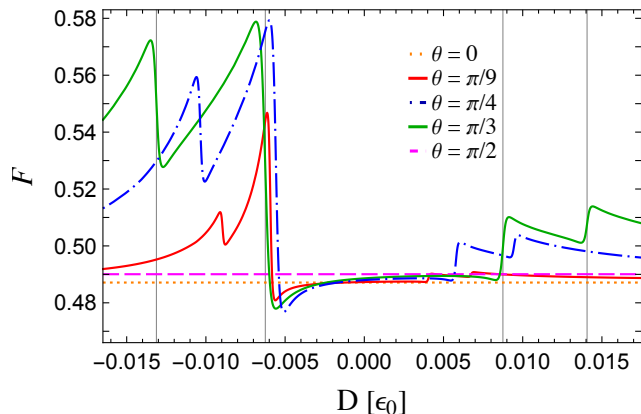


FIG. 3: (Color online) Fano factor F as a function of the uniaxial anisotropy parameter D . The plots are obtained for different tilt angles θ at zero temperature, with $\vec{B} = B\vec{e}_z$. The chemical potentials of the leads are equal to: $\mu_L = 2.5\epsilon_0$ and $\mu_R = 0$. The other parameters are set to: $\Gamma = 0.05\epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $\omega_L = 0.5\epsilon_0$, $J = 0.01\epsilon_0$, $S = 100$.

ing that the zero-frequency ($\Omega = 0$) noise power satisfies the relations $S_{LL}(0) = S_{RR}(0) = -S_{LR}(0) = -S_{RL}(0)$. In experimental configurations zero-frequency noise power spectrum is standardly measured. In the remainder of this article, the zero-frequency noise power $S_{LL} = S_{LL}(0)$ at zero temperature will be discussed, as in this particular case it is contributed only by the shot noise, while thermal noise vanishes.

IV. RESULTS

Now we analyse the behaviour of the charge current I_L , noise power S_{LL} , and Fano factor $F = S_{LL}/e|I_L|$ as

functions of the uniaxial magnetic anisotropy parameter D , bias voltage $eV = \mu_L - \mu_R$, and Larmor frequency ω_L (magnetic field B), focusing on the influence of the tuning anisotropy parameter D on the transport properties of the system. In particular, it will be shown that the anisotropy parameter D can contribute to the controlling and reducing the noise power. One should emphasize that the shot noise is the result of the competition between the positive (or zero) contribution coming from the correlations of currents with the same spins, and negative (or zero) contribution of correlations between charge currents with opposite spins.

In Fig. 2 the average charge current from the left lead I_L and autocorrelation shot noise S_{LL} are presented as functions of the uniaxial magnetic anisotropy parameter D , for five different tilt angles θ , while the corresponding Fano factor F is shown in Fig. 3. The fano factor $F < 1$, so the noise is sub-Poissonian. Immediately, we see that the current, shot noise and consequently the Fano factor are constant for $\theta = 0$ (orange, dotted lines) and $\theta = \pi/2$ (pink, dashed lines). If we look at the expression for the current, given by Eq. (7), we notice that for $\theta = 0$, $\gamma = 0$ as well and the charge current dependence on D vanishes. On the other hand, for $\theta = \pi/2$, the z -component of the molecular spin $S_z = 0$, and hence the current does not depend on the anisotropy parameter D either. For the tilt angle $\theta = \pi/3$ (green line in Fig. 2 and 3) and $D = -0.01312\epsilon_0$ (grid line in Fig. 2 and Fig. 3), corresponding to $\mu_L = \epsilon_2 = 2.5\epsilon_0$, there is a dip-peak feature in the current and a peak-dip feature in the shot noise and Fano factor. Similarly as in the Fano effect,¹⁰³ the peak-dip (dip-peak) characteristics are a manifestation of the destructive quantum interference between the states connected with inelastic tunneling processes involving absorption(emission) of an energy quantum ω and a spin-flip. Namely, there are two tunnelling pro-

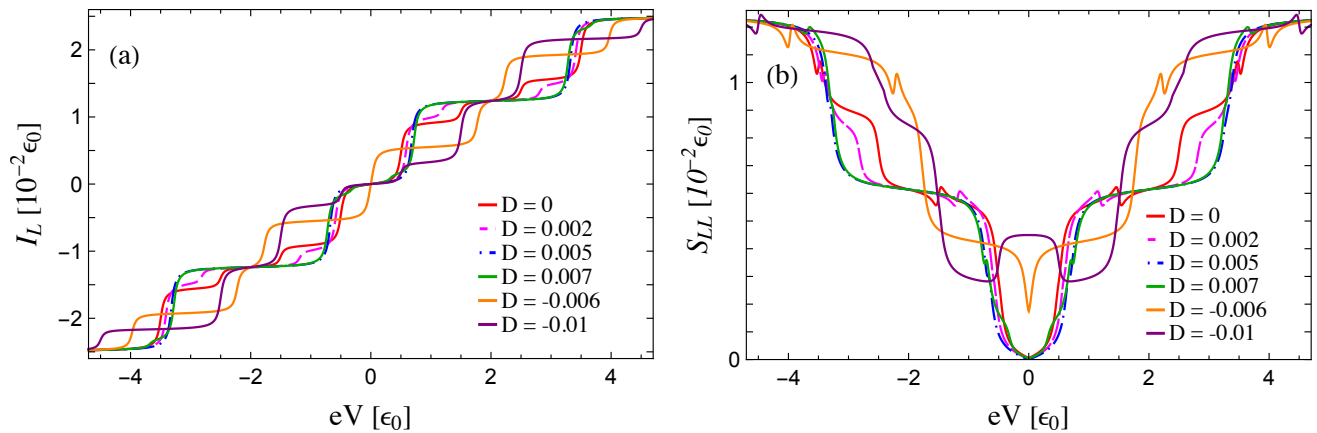


FIG. 4: (Color online) (a) Charge current I_L and (b) autocorrelation shot noise S_{LL} as functions of the applied bias voltage $eV = \mu_L - \mu_R$ with $\mu_{L,R} = \pm eV/2$ and $\vec{B} = B\vec{e}_z$, for different uniaxial magnetic anisotropy parameters D at zero temperature. The other parameters are set to: $\Gamma = 0.05 \epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $\omega_L = 0.5 \epsilon_0$, $J = 0.01 \epsilon_0$, $S = 100$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 . The peak-dip (dip-peak) characteristics in the shot noise S_{LL} as manifestations of the quantum interference effect, and steps in the charge current function I_L and shot noise S_{LL} correspond to resonances $\mu_\xi = \epsilon_i$, with $\xi = L, R$ and $i = 1, 2, 3, 4$.

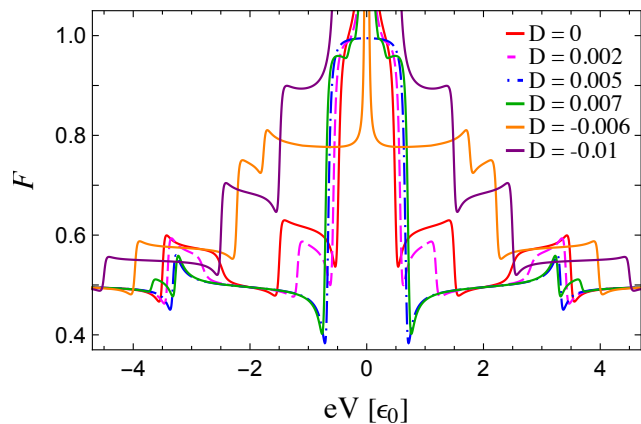


FIG. 5: (Color online) Fano factor F as a function of the applied bias voltage $eV = \mu_L - \mu_R$ with $\mu_{L,R} = \pm eV/2$ and $\vec{B} = B\vec{e}_z$, for different uniaxial magnetic anisotropy parameters D at zero temperature. The other parameters are set to: $\Gamma = 0.05 \epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $\omega_L = 0.5 \epsilon_0$, $J = 0.01 \epsilon_0$, $S = 100$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 .

cesses, one elastic through quasienergy level with energy e.g. ϵ_1 , and the other inelastic through the quasienergy level $\epsilon_2 = \epsilon_1 + \omega$, involving a spin-flip and the emission of the amount energy ω and ending up in the same level ϵ_1 . The two tunnelling pathways destructively interfere and negatively contribute to the shot noise. For this set of parameters, only quasienergy level with energy $\epsilon_3 = -0.5 \epsilon_0$ lies out of the bias-voltage window. However, as the anisotropy parameter D increases, the quasienergy level ϵ_3 moves up the energy scale and enters the bias-voltage window around $D = -0.00625 \epsilon_0$ (another grid line in Fig. 2 and Fig. 3), with $\mu_R = \epsilon_3 = 0$. In this case, all four levels lie within the bias-voltage window, lead-

ing to the minimum and after that the enhancement of the current, and the most prominent peak-dip feature in the noise and Fano factor, where the dips represent their minimum values. With further increase of the anisotropy parameter D , the current and noise approach constant values, and $F \approx 0.49$, but since the quasienergy level ϵ_4 moves down the energy scale, for $D = 0.00875 \epsilon_0$ (the third grid line in Fig. 2 and Fig. 3), it reaches the resonance with μ_R , i.e., $\mu_R = \epsilon_4 = 0$, leading to a decrease of current and a dip-peak in the shot noise. With further increase of D , the level ϵ_4 leaves the bias-voltage window. At $D = 0.01406 \epsilon_0$ (the remaining grid line in Fig. 2 and Fig. 3), the quasienergy level ϵ_1 which increases with the increase of D , is in resonance with μ_L , i.e., $\mu_L = \epsilon_1$, before it leaves the bias-voltage window with further increase of D , resulting in the final decrease in the charge current and dip-peak in the shot noise. All the plots in Fig. 2, except the ones with $\theta = 0$ and $\theta = \pi/2$, show that both charge current and shot noise have minimum values around the value of anisotropy parameter D that corresponds to the entrance of all four quasienergy levels into the bias-voltage window. Both charge current and shot noise are saturated for large values of $|D|$.

The average charge current I_L as a function of the applied bias-voltage eV at zero temperature is plotted for six different values of anisotropy parameter D in Fig. 4(a), where the bias voltage is varied such that $\mu_{L,R} = \pm eV/2$. As the bias voltage increases, a new channel available for electron transport, with an energy ϵ_i , $i \in \{1, 2, 3, 4\}$, enters the bias-voltage window, resulting in a step increase in the current. Since the positions of the quasienergy levels ϵ_i depend on molecular spin anisotropy, for different values of D , the staircase current function will show steps at different values of eV . The shot noise of charge current S_{LL} is

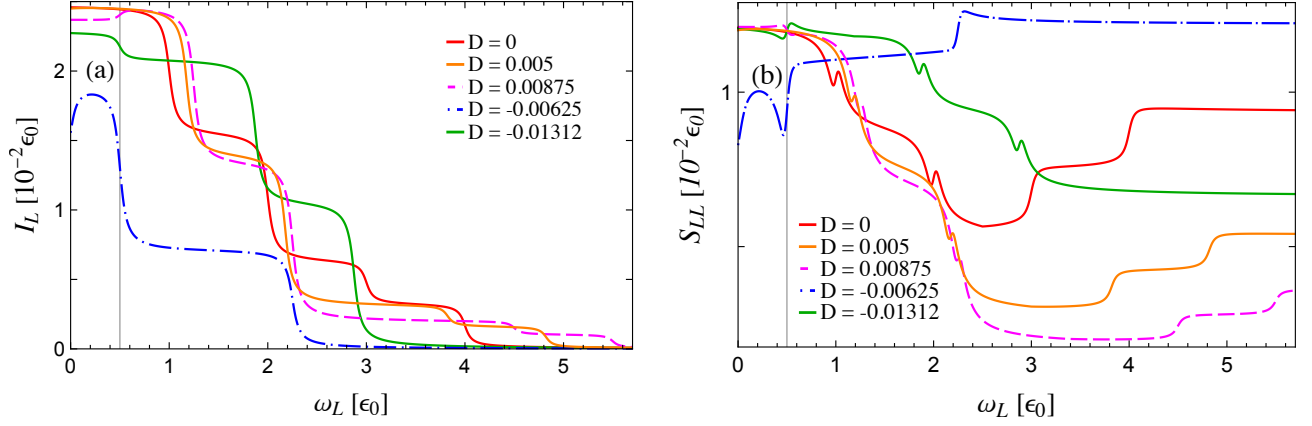


FIG. 6: (Color online) (a) Charge current I_L and (b) autocorrelation shot noise S_{LL} as functions of the Larmor frequency ω_L for different uniaxial magnetic anisotropy parameters D . All plots are obtained at zero temperature with $\vec{B} = B\vec{e}_z$. The chemical potentials of the leads are equal to: $\mu_R = 0$ and $\mu_L = 2.5\epsilon_0$, except for $D = -0.00625\epsilon_0$, where $\mu_L = 1.125\epsilon_0$. The other parameters are set to: $\Gamma = 0.05\epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $J = 0.01\epsilon_0$, $S = 100$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 . All steps in the current I_L , and the corresponding steps and dip-peak features in the noise S_{LL} , denote a resonance $\mu_\xi = \epsilon_i$, with $\xi = L, R$. A distinct dip in the noise S_{LL} and a significant drop of the corresponding current appear for $D = -0.00625\epsilon_0$ (blue dot-dashed line) around $\omega_L = 0.5\epsilon_0$ (grid line), due to the double resonance: $\mu_R = \epsilon_3$ and $\mu_L = \epsilon_4$.

shown in Fig. 4(b). The peak-dip (dip-peak) characteristics, which occur due to the quantum interference, and steps in the noise power S_{LL} , correspond to resonances $\mu_\xi = \pm eV/2 = \epsilon_i$, with $\xi = L, R$ and $i = 1, 2, 3, 4$. Hence, they change their positions with the change of the magnetic anisotropy parameter D . For the given set of parameters: $\omega_L = 0.5\epsilon_0$, $\theta = \pi/3$, and $D = 0.005\epsilon_0$ in Fig. 4 (blue, dot-dashed line), one obtains $\omega = \omega_L - DS = 0$ and there are only two transport channels in this case, with energies $\epsilon = 0.34\epsilon_0$ and $\epsilon t = 1.66\epsilon_0$, available for the elastic tunnelling, denoted by the steps at $\pm eV/2 = \epsilon$ and $\pm eV/2 = \epsilon t$. The average charge current I_L is equal to zero for $eV = 0$, but the noise power is contributed by the inelastic processes in which an electron flips its spin and absorbs an energy ω , leading to the divergence of the Fano factor (see Fig. 5). The noise becomes sub-Poissonian ($F < 1$) as soon as one of the levels ϵ_i enters the bias-voltage window, since the transmission probability increases. After all the levels ϵ_i enter the bias-voltage window, the Fano factor becomes constant $F = 1/2$.¹⁰⁴ In the case of only elastic tunnelling ($D = 0.005\epsilon_0$, $\omega = 0$, blue dot-dashed line in Fig. 5), the Fano factor $F = 1$ for $0 < eV < \epsilon$, since the transmission probability is very low and the currents remain uncorrelated until the first channel available for transport appears. For $D = 0.007\epsilon_0$, $\omega = -0.2\epsilon_0$ (green line in Fig. 5), one notices a dip in the Fano factor and a small peak-dip in the relevant noise at $eV = 0.72\epsilon_0$. This corresponds to $\mu_L = \epsilon_3$, leading to the destructive quantum interference. For $D = 0.007\epsilon_0$, we notice another peak-dip feature due to the quantum interference at $eV = 3.68\epsilon_0$, corresponding to $\mu_L = \epsilon_1$. The other step-like and peak-dip (dip-peak) features in Fig. 4 and Fig. 5 denote energies of the available transport channels $\epsilon_i = \pm eV/2$.

The average charge current I_L and noise S_{LL} as functions of the Larmor frequency ω_L at zero temperature, for several different values of the uniaxial magnetic anisotropy parameter D , are shown in Figs. 6(a) and 6(b). Here, the bias voltage is varied as $eV = \mu_L - \mu_R$, with $\mu_R = 0$, while $\mu_L = 2.5\epsilon_0$, except for the blue dot-dashed lines where $\mu_L = 1.125\epsilon_0$. All steps in the current I_L , as well as steps and dip-peak features in the noise S_{LL} , correspond to a resonance $\mu_\xi = \epsilon_i$. The dip-peak features are a result of the competition between positive correlations of the currents with the same spin, and negative correlations of the currents with the opposite spins, with an impact of the quantum interference effect for the interfering tunnelling pathways. At $\omega_L = 0$, for $D = -0.00625\epsilon_0$ and $\mu_L = 1.125\epsilon_0$ [Fig. 6 (blue dot-dashed lines)], both current and noise increase, since quasienergy level ϵ_1 enters the bias-voltage window, $\mu_L = \epsilon_1$, while $\epsilon_2 = 1.75\epsilon_0$, $\epsilon_3 = 0.25\epsilon_0$ and $\epsilon_4 = 0.875\epsilon_0$. In Fig. 6(b), around $\omega_L = 0.5\epsilon_0$ (grid line), one observes a small peak-dip for $D = 0.00875\epsilon_0$ (pink line), due to the fact that $\epsilon_4 = \mu_R$, while for the anisotropy parameter $D = -0.01312\epsilon_0$ there is a dip-peak structure, as $\mu_L = \epsilon_2$, showing the impact of the destructive quantum interference effect (green line), and for $D = -0.00625\epsilon_0$, the two chemical potentials μ_R and μ_L are in resonance with two levels connected with spin-flip events, ϵ_3 and ϵ_4 , resulting in a dip with higher magnitude (blue dot-dashed line). Here, due to the destructive interference effect, the negative contribution of the correlations between the currents with opposite spins shows a dip-peak structure, while the positive contribution of the correlations of the charge currents with the same spin shows a positive dip, resulting in the higher dip in the noise S_{LL} around $\omega_L = 0.5\epsilon_0$. In all the

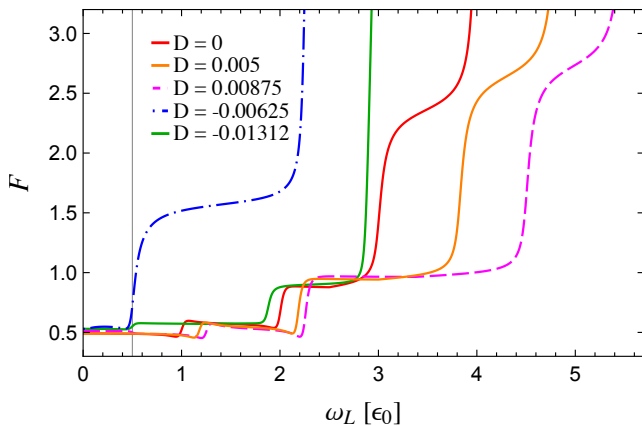


FIG. 7: (Color online) Fano factor F as a function of the Larmor frequency ω_L for different uniaxial magnetic anisotropy parameters D . All plots are obtained at zero temperature with $\vec{B} = B\vec{e}_z$. The chemical potentials of the leads are equal to: $\mu_R = 0$ and $\mu_L = 2.5\epsilon_0$, except for $D = -0.00625$ (blue dot-dashed line), where $\mu_L = 1.125\epsilon_0$. The other parameters are set to: $\Gamma = 0.05\epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $J = 0.01\epsilon_0$, $S = 100$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 .

plots in Fig. 6, for ω_L and D such that one remaining quasienergy level ϵ_i within the bias-voltage window is in resonance with the chemical potential of one of the leads, one notices the final step decrease in the current I_L , and the final step increase in S_{LL} (red, orange, pink dashed, and blue dot-dashed line) or a dip-peak structure (green line). For $D = -0.0625\epsilon_0$ and $\omega_L = 2.25\epsilon_0$ (blue dot-dashed line) the remaining level within the bias-voltage window ϵ_1 is in resonance with μ_R , $\epsilon_1 = \mu_R$, whereas, e.g., for $D = -0.01312\epsilon_0$ and $\omega_L = 2.87\epsilon_0$ (green line), the energy of the only level within the bias-voltage window equals $\epsilon_4 = \mu_L$. With further increase of ω_L , all for levels ϵ_i lie out of the bias-voltage window and the current $I_L \rightarrow 0$, while the noise power becomes a constant due to the inelastic processes, and the Fano factor F presented in Fig. 7 indicates the super-Poissonian noise, $F > 1$. Again, one can see that $F \rightarrow 1/2$ if all the quasienergy levels lie within the bias voltage window,¹⁰⁴ e.g., for $D = 0.005\epsilon_0$ and $\omega \leq 1.18\epsilon_0$ (orange line), while the Fano factor F slightly increases with the increase of ω_L , since three levels remain within the bias voltage window, and the noise is sub-Poissonian. With further increase of ω_L the two levels ϵ_1 and ϵ_4 remain within the bias-voltage window, and the uncorrelated currents lead to $F \rightarrow 1$. Finally, with only one quasienergy level within the bias-voltage window, the current decreases and the noise becomes super-Poissonian. For the magnetic anisotropy parameter $D = -0.00625\epsilon_0$ (blue dot-dashed line) the noise becomes super-Poissonian already around Larmor frequency $\omega_L = 0.5\epsilon_0$, since for $0.5\epsilon_0 < \omega_L \leq 2.25\epsilon_0$ only level ϵ_1 lies within the bias-voltage window.

In Fig. 8 the dependence of the autocorrelation charge-current noise S_{LL} on frequency ω_L is plotted for several values of the uniaxial magnetic anisotropy parameter D

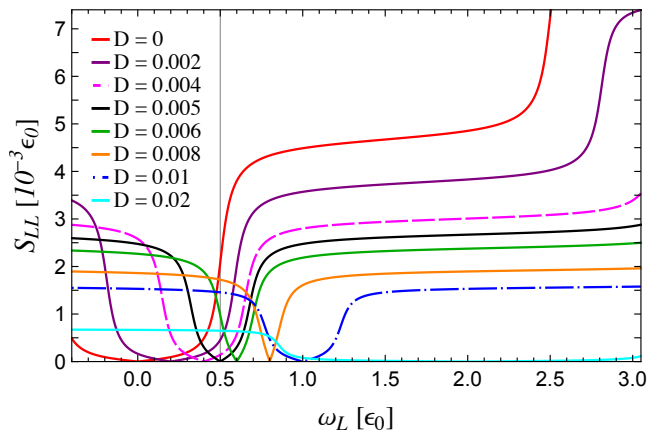


FIG. 8: (Color online) Shot noise of charge current S_{LL} as a function of the Larmor frequency ω_L for different uniaxial magnetic anisotropy parameters D at zero-bias voltage. All plots are obtained at zero temperature with $\vec{B} = B\vec{e}_z$. The chemical potentials of the leads are equal and set to: $\mu_L = \mu_R = 0.25\epsilon_0$. The other parameters are set to: $\Gamma = 0.05\epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $J = 0.01\epsilon_0$, $S = 100$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 . The noise S_{LL} is suppressed for $\omega = 0$, i.e., $D = \omega_L/2S_z$.

and equal chemical potentials of the leads, $\mu_L = \mu_R = \mu = 0.25\epsilon_0$, at zero temperature. In the case of the isotropic molecular spin with magnetic anisotropy parameter $D = 0$ (red line in Fig. 8), the shot noise S_{LL} is an even, positive function of Larmor frequency ω_L at zero-bias conditions $eV = 0$, $S_{LL}(\omega_L) = S_{LL}(-\omega_L)$,⁷⁹ whereas if the molecular spin is anisotropic ($D \neq 0$), the shot noise is an even, positive function of the frequency ω , $S_{LL}(\omega) = S_{LL}(-\omega)$. In all the plots each step-like increase or decrease correspond to a resonance between chemical potential of the leads and one of the levels available for electron transport (not all are shown). For instance, if we take Larmor frequency $\omega_L = 0.5\epsilon_0$ (marked by a vertical grid line), there is a step-like increase for the magnetic anisotropy parameter $D = 0$ (red line) since the chemical potential μ is in resonance with quasienergy level ϵ_3 , $\mu = \epsilon_3$. Similar step for $D = 0.002\epsilon_0$ occurs around $\omega_L = 0.586\epsilon_0$, where $\mu = \epsilon_3$ (purple line). For $\omega_L = 0.5\epsilon_0$ and $D = 0.005\epsilon_0$, the resulting $\omega = 0$, with only two electronic levels available for charge transport since $\epsilon_1 = \epsilon_2$, $\epsilon_3 = \epsilon_4$, and the charge-current shot noise S_{LL} monotonically decreases around $\omega_L = 0.5\epsilon_0$, drops to zero at $\omega_L = 0.5\epsilon_0$ (intersection between grid line and black line), then monotonically increases. Similarly, the charge current noise S_{LL} is equal to zero at $\omega_L = 0.6\epsilon_0$, for $D = 0.006\epsilon_0$ (green line), at $\omega_L = 0.8\epsilon_0$, for $D = 0.008\epsilon_0$ (orange line), and at $\omega_L = \epsilon_0$, for $D = 0.01\epsilon_0$ (blue dot-dashed line). For $D = 0.006\epsilon_0$, the quasienergy level ϵ_4 is in resonance with μ , $\mu = \epsilon_4$ at $\omega_L = 0.5\epsilon_0$ and one observes a step-like decrease (intersection between grid line and green line in Fig. 8). With further increase of the uniaxial magnetic anisotropy parameter D , the shot noise S_{LL} decreases (cyan line in

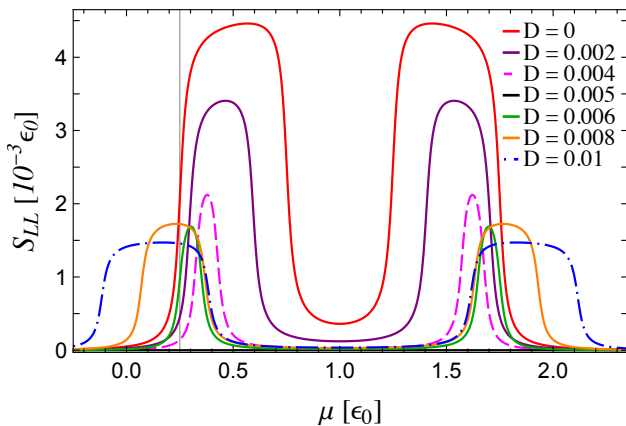


FIG. 9: (Color online) Shot noise of charge current S_{LL} at zero-current conditions, as a function of the chemical potential of the leads $\mu = \mu_L = \mu_R$, for different axial magnetic anisotropy parameters D . All plots are obtained at zero temperature with $\vec{B} = B\vec{e}_z$. The other parameters are set to: $\Gamma = 0.05 \epsilon_0$, $\Gamma_L = \Gamma_R = \Gamma/2$, $J = 0.01 \epsilon_0$, $S = 100$, Larmor frequency $\omega_L = 0.5 \epsilon_0$, and $\theta = \pi/3$. All energies are given in the units of ϵ_0 . The shot noise S_{LL} is positive between levels connected with spin-flips for $\omega \neq 0$, i.e., $D \neq \omega_L/S$.

Fig. 8) and for a sufficiently large D , drops to zero.

The autocorrelation shot noise of charge current S_{LL} as a function of chemical potential of the metallic leads at zero-bias conditions $\mu = \mu_L = \mu_R$, for several values of the uniaxial magnetic anisotropy parameter D and Larmor frequency $\omega_L = 0.5 \epsilon_0$ at zero temperature, is shown in Fig. 9. Since the contribution of the correlations between currents with the same spin is dominant, the noise S_{LL} takes positive values for $\omega = \omega_L - 2DS_z \neq 0$, i.e., for $D \neq \omega_L/2S_z$ in the regions between quasienergy levels connected with spin-flip events, taking into account the level broadening Γ . The grid line in Fig. 9 at $\mu = 0.25 \epsilon_0$, corresponding to the grid line in Fig. 8 at $\omega_L = 0.5 \epsilon_0$, intersects with all the plots showing that the positive charge-current noise S_{LL} is reduced with the increase of the anisotropy parameter D . The noise drops to zero for $\omega = 0$, when the magnetic anisotropy constant $D = \omega_L/2S_z = 0.005 \epsilon_0$ (black line in Fig. 9). With further increase of the anisotropy parameter D , the frequency $\omega < 0$, i.e., the direction of the precession is changed, the anisotropy parameter $D > \omega_L/2S_z$, and the shot noise S_{LL} takes positive low values between levels connected with spin-flip events (green, orange, and blue dot-dashed lines in Fig. 9) compared to the one at the highest positive frequency $\omega = \omega_L$ (isotropic spin, red line). In order to reduce the shot noise S_{LL} at zero-bias conditions, one needs to increase the magnetic anisotropy parameter D and either slow down the precession of the molecular spin, or change the direction of the spin precession with respect to the Larmor precession. With further increase of the magnetic anisotropy parameter, for a sufficiently large D , the shot noise S_{LL} becomes entirely suppressed and drops to zero.

V. CONCLUSIONS

In this article, the characteristics of charge transport through a single molecular orbital in the presence of a precessing anisotropic molecular spin in a magnetic field, connected to two noninteracting metallic leads, was theoretically studied. The Larmor frequency is modified by a term with the uniaxial magnetic anisotropy parameter of the molecular spin, and the resulting precession with frequency $\omega = \omega_L - 2DS_z$ is externally kept undamped. The expressions for charge current and current noise were obtained using the Keldysh nonequilibrium Green's functions method.

The results show rich transport characteristics at zero temperature. The quantum interference between the states connected with precession-assisted inelastic tunnelling, involving absorption(emission) of an energy ω and a spin-flip, result in peak-dip (dip-peak) features in the shot noise. Each resonance between a chemical potential and an anisotropy dependent quasienergy level is visible in a transport measurement in the form of e.g. steps, and peak-dip (dip-peak) features, and can be varied by tuning the anisotropy. The correlations between the same-spin (opposite-spin) currents are positive (negative) or zero, and are particularly interesting at zero-bias conditions since the resulting shot noise is positive for chemical potentials between couples of quasienergy levels, which are connected by the precession-assisted inelastic tunnelling accompanied by a spin-flip. If the anisotropy parameter of the molecular magnet is large enough to decrease the precession frequency of the molecular spin or change the precession direction of the molecular magnetization with respect to the Larmor precession, the noise is reduced. Additionally, the anisotropy parameter can be adjusted to suppress the precession frequency, so that the resulting shot noise vanishes. It was shown that the charge current and shot noise can be controlled by a proper adjustment of the anisotropy parameter of the molecular magnet and reach their saturation if this parameter takes large values at nonzero bias-voltage.

Taking into consideration that the charge transport in the given setup with the anisotropic molecular magnet can be manipulated by the uniaxial magnetic anisotropy of the molecular spin, and other parameters, the results of this study may be useful in the field of single-molecule electronics and spintronics. It might be useful for magnetic storage applications to study the charge- and spin-transport properties using a setup with a molecular spin modelled as a quantum object in the future.

Acknowledgments

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